



DMG6968U

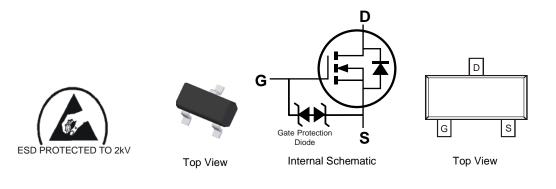
#### N-CHANNEL ENHANCEMENT MODE MOSFET

### Features

- Low On-Resistance
  - $25m\Omega @ V_{GS} = 4.5V$
  - 29mΩ @ V<sub>GS</sub> = 2.5V
  - 36mΩ @ V<sub>GS</sub> = 1.8V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



### Ordering Information (Note 5)

Part Number	Compliance	Case	Packaging
DMG6968U-7	Standard	SOT23	3000/Tape & Reel
DMG6968UQ-7	Automotive	SOT23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

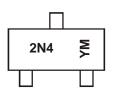
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally

- the same, except where specified. For more information, please refer to https://www.diodes.com/quality/product-compliance-definitions/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



2N4 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

#### Date Code Key

Notes:

Year	2009		2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	W		E	F	G	Н		J	K	L	М	N
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 6)	$\begin{array}{ c c c } Steady & T_A = +25^{\circ}C \\ State & T_A = +70^{\circ}C \end{array}$		ID	6.5 5.2	A
Pulsed Drain Current			I <sub>DM</sub>	30	А

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	1.3	W
Thermal Resistance, Junction to Ambient @ T <sub>A</sub> = +25°C	R <sub>0JA</sub>	157	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)									
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	20			V	$V_{GS} = 0V, I_D = 250 \mu A$		
Zero Gate Voltage Drain Current	$T_J = +25^{\circ}C$	I <sub>DSS</sub>	_		1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$		
Gate-Source Leakage	I <sub>GSS</sub>	_		±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$			
Gate-Source Breakdown Voltage	BV <sub>SGS</sub>	±12	_	_	V	$V_{DS} = 0V$ , $I_G = \pm 250 \mu A$			
ON CHARACTERISTICS (Note 7)									
Gate Threshold Voltage		V <sub>GS(TH)</sub>	0.5		0.9	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$		
				21	25		$V_{GS} = 4.5V, I_D = 6.5A$		
Static Drain-Source On-Resistance		Rds(on)	_	23	29	mΩ	$V_{GS} = 2.5V, I_D = 5.5A$		
				28	36		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 3.5A		
Forward Transfer Admittance		Y <sub>fs</sub>		8		S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 5A		
DYNAMIC CHARACTERISTICS (Note	8)					•			
Input Capacitance		Ciss		151		pF			
Output Capacitance		Coss	_	91	_	pF	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance		Crss	_	32		pF			
Total Gate Charge	arge			8.5		nC			
Gate-Source Charge		Q <sub>gs</sub>		1.6		nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 6.5		
Gate-Drain Charge		Q <sub>gd</sub>		2.8		nC	7		
Turn-On Delay Time		t <sub>D(ON)</sub>	_	54	—	ns			
Turn-On Rise Time		t <sub>R</sub>	_	66		ns	$V_{DD} = 10V, V_{GS} = 4.5V,$		
Turn-Off Delay Time		t <sub>D(OFF)</sub>		613		ns	$R_L = 10\Omega, R_G = 6\Omega, I_D = 1A$		
Turn-Off Fall Time		t <sub>F</sub>	_	205		ns	1		

 Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal vias to bottom layer 1 inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing. Notes:



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T<sub>A</sub> = 85°C

T<sub>A</sub> = 150°C

T<sub>A</sub> = 125°C

 $T_A = 85^{\circ}C$ 

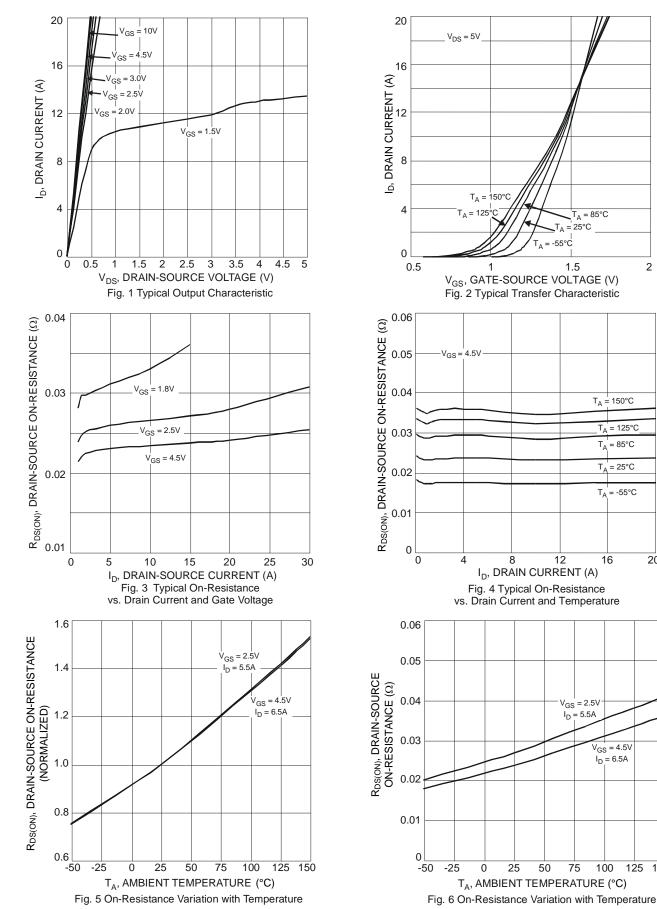
= 25°C

 $T_A = -55^{\circ}C$ 

16

 $V_{GS} = 4.5V$  $I_{D} = 6.5A$ 

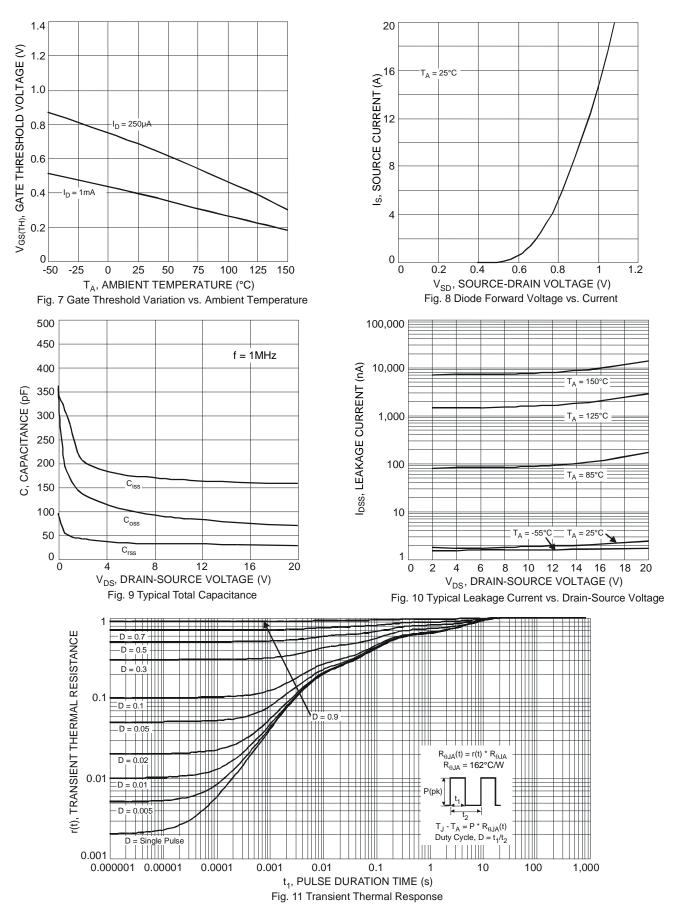
20



100 125 150

75

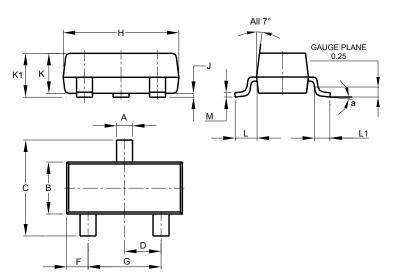






## **Package Outline Dimensions**

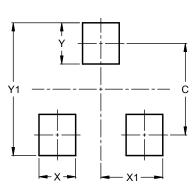
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
К	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

#### SOT23



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